

Part Number: DL25-TO-X-XX-X Product State: Production Build

25G DFB Laser TOSA Package

Description

A 25 Gb/s edge emitting laser diode in a TO-can package. The Multi-quantum well distributed feedback (DFB) laser is directly modulated (DML) with a RF signal. This device comes with a built in Photodiode monitor to allow of Auto-bias operation. Various build configurations allow the user to customize the optical connector as well as the mounting brackets for the device. Optics sub-assembly includes isolator.

Features

- TO-Can Package
- Single mode Pigtail cable
- 1310 nm CW
- High SFDR
- Built-in InGaAs monitor Photodiode
- Wide Temperature operating range
- Built in Optical Isolator



Applications

- 5G
- Datacenters
- RF over Fiber (RFoF)





IMPORTANT NOTICE: more Information on warranty, changes, rights, notices, and other information are presented at the end of this data sheet. If the sheet is not present, refer to <u>www.nuphotonics.com</u> for the company issued data sheet.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Peak Wavelength	λ	1304.5	1310	1317.5	nm	
		1545	1550	1557		
Threshold Current	l _{th}		6	13	mA	T=25 °C
Front Power	Po	1			mW	$I_f = I_{th} + 20 \text{ mA}$
Slope Efficiency	η	0.2	0.3		W/A	I _f = I _{th} + 20 mA
Series Resistance	R			10	Ohms	P _o = 8 mW
Forward Voltage	V _f		1.1	1.5	V	$I_f = I_{th} + 20 \text{ mA}$
Spectral Wavelength Width (RMS)	Δλ		0.3	0.5	nm	P _o = 5mW at -20 dB
Frequency Bandwidth	BW	10			GHz	Designed RF board.
Side Mode Suppression Ratio	SMSR	30			dB	
Monitor Current	Im	0.4	0.5	1.0	mA	lop = 30 mA
Optical Return Loss	ORL			-30	dB	CW = 1310 nm
Tracking Error	Те	-1.5		1.5	dB	-40 – 80 °C

Laser Electro-Optical Characteristics (T $_{op}$ 23 ± 3°c, unless otherwise specified)

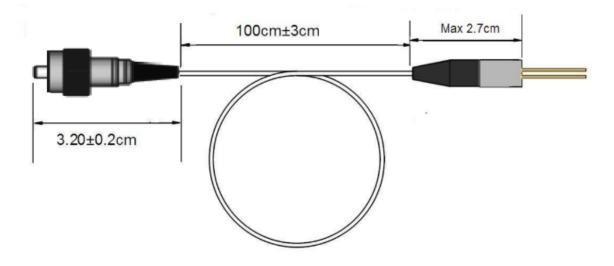
Laser Absolute Maximum Ratings

Parameter	Symbol	Condition	Min.	Max.	Unit
Voltage	V			1.8	V
Forward Current	I _F			80	mA
Storage Temperature	T _{stg}		-25	90	°C
Storage Humidity	H _{stg}			85	% r.H.
Operating Temperature	T _{op}		-25	85	°C
Soldering Temperature	T _{st}	60 sec		200	°C
ESD Susceptibility		HBM	100		V

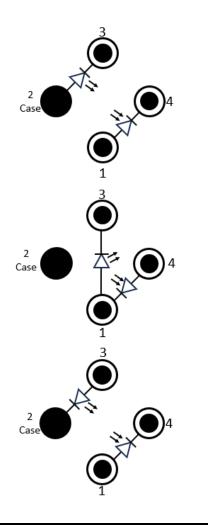
Operating at maximum operating specs for prolong periods of time will damage the device.



Device Dimensions



Device Pin Configuration (Bottom View)



Build A: DFB Laser Anode Case Ground

Pin Function:

- 1) Monitor PD Anode
- 2) Laser Anode Tied to Case Ground
- 3) Laser Cathode
- 4) Monitor PD Cathode

Build B: Tied Photodiode-Laser Build

Pin Function:

- 1) Laser Anode/ Monitor PD Cathode
- 2) Case Ground
- 3) Laser Cathode
- 4) Monitor PD Anode

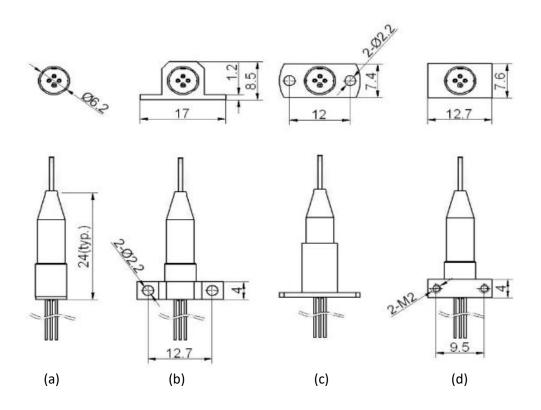
Build C: DFB Laser Cathode Case Ground

Pin Function:

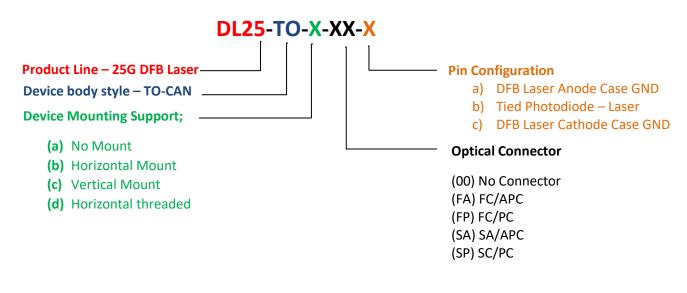
- 1) Monitor PD Anode
- 2) Laser Cathode Tied to Case Ground
- 3) Laser Anode
- 4) Monitor PD Cathode



Build Configurations – Mounting Support



Device Nomenclature





Inquiry Information

Sales: All inquiries regarding sales please contact <a>Sales@NuPhotonics.com

General: If you are interested in a custom solution, general information, or engineering related information please contact <u>Inquiry@NuPhotonics.com</u>



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Definitions: Product State

Alpha Build: Devices in Alpha build are in internal engineering build and testing stages. Major changes may happen for production build.

Beta Build: Devices in Beta build are for external customer and engineering sample testing stages. Minor changes may happen for production build.

Production Build: Customer ready devices. Small appearance changes may occur between devices.

Obsolete: Currently not supported.

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